

# L9637D

# **ISO 9141 INTERFACE**

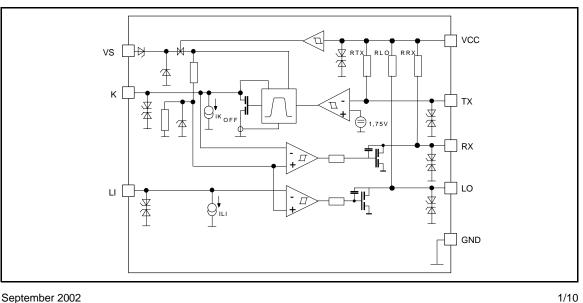
- OPERATING POWER SUPPLY VOLTAGE RANGE 4.5V  $\leq$  V<sub>S</sub>  $\leq$  36V (40V FOR TRANSIENTS)
- REVERSE SUPPLY (BATTERY) PROTECTED DOWN TO  $V_S \ge -24V$
- STANDBY MODE WITH VERY LOW CUR-RENT CONSUMPTION IS<sub>SB</sub> 1µA @ V<sub>CC</sub> 0.5V
- LOW QUIESCENT CURRENT IN OFF CON-DITION IS<sub>OFF</sub> = 120μA
- TTL COMPATIBLE TX INPUT
- BIDIRECTIONAL K-I/O PIN WITH SUPPLY VOLTAGE DEPENDENT INPUT THRESHOLD
- OVERTEMPERATURE SHUT DOWN FUNC-TION SELECTIVE TO K-I/O PIN
- WIDE INPUT AND OUTPUT VOLTAGE RANGE -24V  $\leq$  V<sub>K</sub>  $\leq$  V<sub>S</sub>
- K OUTPUT CURRENT LIMITATION, TYP  $I_{K} = 60 \text{mA}$
- DEFINED OFF OUTPUT STATUS IN UNDER-VOLTAGE CONDITION AND VS OR GND IN-TERRUPTION
- CONTROLLED OUTPUT SLOPE FOR LOW EMI
- HIGH INPUT IMPEDANCE FOR OPEN V<sub>S</sub> OR GND CONNECTION



- DEFINED OUTPUT ON STATUS OF LO OR RX FOR OPEN LI OR K INPUTS
- DEFINED K OUTPUT OFF FOR TX INPUT OPEN
- INTEGRATED PULL UP RESISTORS FOR TX, RX AND LO
- EMI ROBUSTNESS OPTIMIZED

#### DESCRIPTION

The L9637D is a monolithic integrated circuit containing standard ISO 9141 compatible interface functions.



#### **BLOCK DIAGRAM**

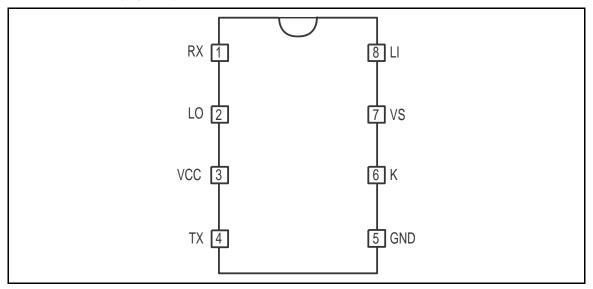
# L9637D

## ABSOLUTE MAXIMUM RATINGS (No damage or latch)

Symbol	Parameter	Value	Unit
Vs	Supply Voltage ISO transients t = 400ms	-24 to +36 -24 to +40	V V
V <sub>CC</sub>	Stabilized Voltage	-0.3 to +7	V
∆Vs/dt	Supply Voltage transient	-10 to +10	V/µs
V <sub>LI, K</sub>	Pin Voltage	-24 to $V_S$	V
V <sub>LO, RX, TX</sub>	Pin Voltage	-24 to V <sub>CC</sub>	V

Note: Max. ESD voltages are  $\pm 2kV$  with human body model C = 100pF, R = 1.5k corresponds to maximum energy dissipation 0.2mJ according to MIL883C.

# **PIN CONNECTION** (Top view)



## THERMAL DATA

Symbol Parameter		Min.	Тур.	Max.	Unit
T <sub>JSDon</sub> T <sub>JSDoff</sub>	Temperature K shutdown switch on threshold Temperature K shutdown switch off threshold	160 150		200 200	ဂံဂံ
R <sub>th j-amb</sub>	Thermal steady state junction to ambient resistance	130	155	180	°C/W

#### **PIN DESCRIPTION**

N.	Name	Function			
1	RX	Output for K as input			
2	LO	Output L comparator			
3	VCC	Stabilized voltage supply			
4	ТΧ	Input for K as output			
5	GND	Common GND			
6	К	Bidirectional I/O			
7	VS	Supply voltage			
8	LI	Input L comparator			

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**ELECTRICAL CHARACTERISTICS** (The electrical characteristics are valid within the below defined operating conditions, unless otherwise specified. The function is guaranteed by design until  $T_{JSDon}$  temperature shutdown switch-on-threshold.)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vs	Supply Voltage		4.5		36	V
Vcc	Stabilized Voltage		3		7	V
Тj	Junction temperature		-40		150	°C
I <sub>CC</sub>	Supply V <sub>CC</sub> Current	$V_{CC} \le 5.5V$ ; VLI,VTX = 0V		1.4	2.3	mA
		$\begin{array}{l} VK \geq VK_{high};  VLI \geq VLI_{high} \\ VTX = V_{CC} @ \ V_{CC} \leq 5.5 V \end{array}$	-5	<1	5	μΑ
IS <sub>ON</sub>	Supply VS Current	$V_{S} \le 16V; VLI, VTX = 0V$		1.2	3	mA
IS <sub>OFF</sub>		$ \begin{array}{l} VK \geq VK_{high};  VLI \geq VLI_{high} \\ VTX \geq VTX_{high} @ V_S \leq 12V \end{array} $		120	220	μA
IS <sub>SB</sub>		$V_{CC} \leq 0.5 V @ V_S \leq 12 V$		<1		μA
VK <sub>low</sub>	Input Voltage Low state	RX output status LOW $4.5V \le V_S \le 18V$	-24		0.45V <sub>S</sub>	V
		RX output status LOW 18V < V <sub>S</sub>	-24		8	V
VK <sub>high</sub>	Input Voltage High state	RX output status HIGH $4.5V \le V_S \le 18V$	0.55V <sub>S</sub>		Vs	V
		RX output status HIGH 18V < V <sub>S</sub>	12		Vs	V
VK <sub>hys</sub>	Input Threshold Hysteresis	Input Threshold Hysteresis VK <sub>high</sub> - VK <sub>low</sub>		0.025 V <sub>S</sub>	0.8	V
IK <sub>off</sub>	Input Current	$ \begin{array}{c} @ \ VTX \geq VTX_{high} \\ VK \leq V_S  V_S, \ V_{CC} \geq 0 \\ V_S, \ V_{CC} = open \end{array}  or \label{eq:VTX}$	-5	4	25	μΑ
RK <sub>ON</sub>	Output ON Impedance			10	30	Ω
IK <sub>SC</sub>	Short Circuit Current		30	60	100	mA
VTXlow	Input voltage LOW state		-24		1	V
VTX <sub>high</sub>	Input voltage HIGH state		2.5		Vcc	V
RRX <sub>ON</sub> RLO <sub>ON</sub>	Output ON Impedance	$ \begin{array}{l} VK \leq VK_{low}; \ VLI \leq VLI_{low} \\ V_S \geq 6.5V \ I_{RX, \ LO} \geq 1mA \end{array} \  \  1) \end{array} $		40	90	Ω
IRX <sub>SC</sub> ILO <sub>SC</sub>	Output Short Circuit Current		9	20	35	mA
VRX <sub>H</sub> VLO <sub>H</sub>	Output Voltage HIGH state	$\begin{array}{l} 10M\Omega \leq R_{LRX} \\ 10M\Omega \leq R_{LLO} \end{array}$	V <sub>CC</sub> - 0.25	V <sub>CC</sub> - 0.1	V <sub>CC</sub>	V
RLO RRX	Output pull-up resistance	$\begin{array}{l} \text{Output status = (HIGH)} \\ \text{-0.15V} \leq \text{VLO} \leq \text{V}_{\text{CC}} + 0.15\text{V} \\ \text{-0.15V} \leq \text{VRX} \leq \text{V}_{\text{CC}} + 0.15\text{V} \end{array}$	5	10	20	KΩ
RTX	Input pull up resistance	$-0.15V \leq VTX \leq V_{CC} + 0.15V$	10	20	40	KΩ
VLI <sub>low</sub>	Input voltage LOW state	LO output status LOW $4.5V \le V_S \le 18V$	-24		0.45V <sub>S</sub>	V
		LO output status LOW 18V < $V_S$	-24		8	V
VL <sub>high</sub>	Input voltage HIGH state	LO output status HIGH $4.5V \le V_S \le 18V$	0.55V <sub>S</sub>		VS	V
		LO output status HIGH 18V < $V_S$	12		VS	V
VLI <sub>hys</sub>	Input threshold hysteresis	VLI <sub>high</sub> - VLI <sub>low</sub>		0.025V <sub>S</sub>	0.8	V
ILI	Input current	$\begin{array}{ccc} VLI \leq V_S, \ V_S, \ V_{CC} \geq 0 & \text{or} \\ & V_S, \ V_{CC} = \text{open} \end{array}$	-5	4	25	μΑ

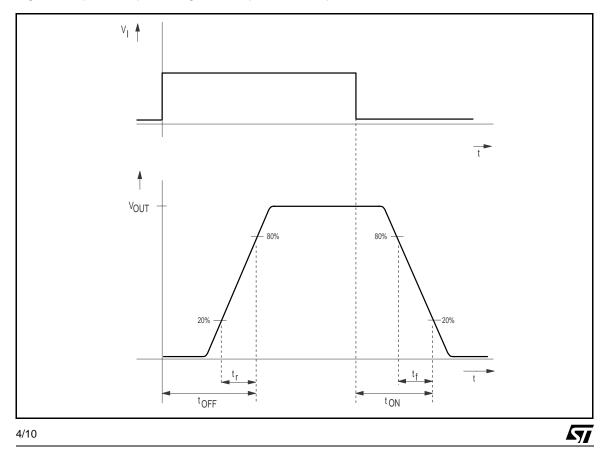
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Symbol	Parameter	Parameter Test Condition		Тур.	Max.	Unit
C <sub>Ki, LO, RX</sub>	Internal output capacities				20	pF
f <sub>LI-LO</sub> fĸ-rx f <sub>TX-k</sub>	$\begin{array}{ll} \mbox{Transmission Frequency} & 9V < V_S < 16V \\ (external loads) \\ R_{KO} = 510\Omega, \ C_K \leq 1.3nF \\ \mbox{in active mode see Fig. 3} \end{array}$		50	100		kHz
t <sub>rLI-LO</sub> t <sub>rK-RX</sub> t <sub>rTX-K</sub>	Rise Time	for the definition of tr, t <sub>f</sub> see Fig.1.		2	6	μs
t <sub>fLI-LO</sub> t <sub>fK-RX</sub> t <sub>fTX-K</sub>	Fall Time	$9V < V_S < 16V$ (external loads) $R_{KO} = 510\Omega$ , $C_K \le 1.3nF$		2	6	μs
toff,li-lo toff,k-rx toff,tx-k	Switch OFF time	for the definition of ton, $t_{\text{OFF}}$ see Fig.1.		4	17	μs
t <sub>on,li-lo</sub> t <sub>on,k-rx</sub> t <sub>on,tx-k</sub>	Switch ON time	$9V < V_S < 16V$ (external loads) $R_{KO} = 510\Omega$ , $C_K \le 1.3nF$ (inactive mode see Fig. 3)		4	17	μs

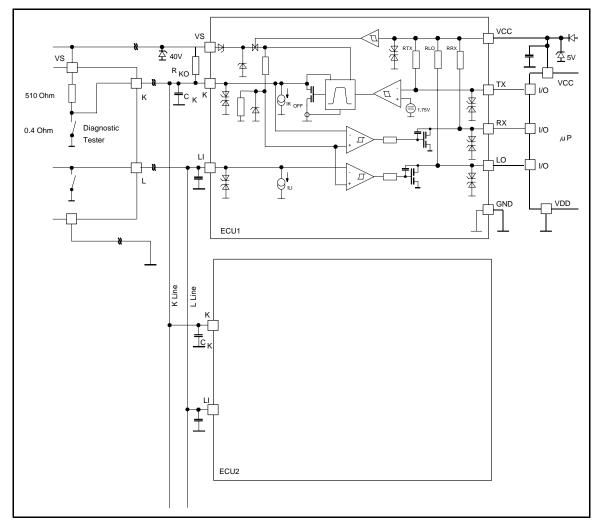
## ELECTRICAL CHARACTERISTIC (continued)

1) For output currents lower than this value a series protection diode can become active. See also Fig. 4 and 5.

Figure 1: Input to Output Timings and Output Pulse Shape.



#### Figure 2: ISO Application Circuit



#### FUNCTIONAL DESCRIPTION

The L9637D is a monolithic bus driver designed to provide bidirectional serial communication in automotive diagnostic applications according to the specification "Diagnostic Systems ISO9141".

The device provides a bidirectional link, called K, to the V<sub>Bat</sub> related diagnosis bus. It also includes a separate comparator L which is also able to be linked to the V<sub>Bat</sub> bus. The input TX and output RX of K are related to V<sub>CC</sub> with her integrated pull up resistances. Also the L comparator output LO has a pull up resistance connected to V<sub>CC</sub>.

The maximum external pull up resistance at K related to V<sub>S</sub> should not be higher than  $R_{KO} \le 5K\Omega$  to achieve clear output ON conditions.

All V<sub>Bat</sub> bus defined inputs LI and K have supply voltage dependent thresholds together with suf-

ficent hysteresis to suppress line spikes. These pins are protected against overvoltages, shorts to GND and V<sub>S</sub> and can also be driven beyond V<sub>S</sub> and GND. These features are also given for TX, RX and LI only taking into account the behaviour of the internal pull up resistances. The thermal shut down function switches OFF the K output if the chip temperature increases above the thermal shut down threshold. To reactivate K again the chip temperature must decrease below the K switch ON temp. To achieve no fault for Vs undervoltage conditions the outputs will be switched OFF and stay at high impedance. The device is also protected against reverse battery condition. During lack of Vs or GND all pins shows high impedance characteristic. To realize a lack of the Vs related bus line LI and K the outputs LO and RX shows defined ON status.

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Supressing all 4 classes of "Schaffner" signals all pins can be load with short energy pulses of max.  $\pm 0.2 mJ$ . All these features together with a high possible baud rate >50Kbaud, controlled output slopes for low EMI, a wide power supply voltage range and a very small quiescent current during OFF (TX LI K=High) condition IS<sub>off typ</sub>  $\leq$  120µA, and a real standby function with zero power consumption IS<sub>SB typ</sub>  $\leq$  1µA during system depowering V<sub>CC</sub>  $\leq$  0.5V make this device high efficient for automotive bus system.

After wake up of the system from OFF or SB condition the first output signal will have an additional delay time  $td_{typ} \le 5\mu s$  see also Fig. 3.

The typical output voltage behaviour for the K, LO, RX outputs as a function of the output current is shown in Fig.4. Fig.5 shows a waveform of the output signal when the low level changes from  $R_{ON} * I_{OUT}$  to  $I_{OUT} * 2 * R_{ON} + U_{BE}$  state. This variation occurs due to too low output current or after a negative transient forced to the output or to the supply voltage line.

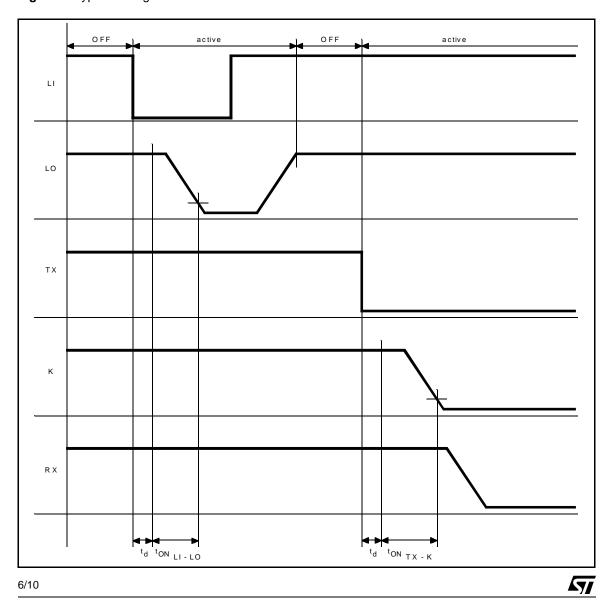


Figure 3: Typical timing for mode transitions.

Figure 4: Output Characteristics at K, LO, RX.

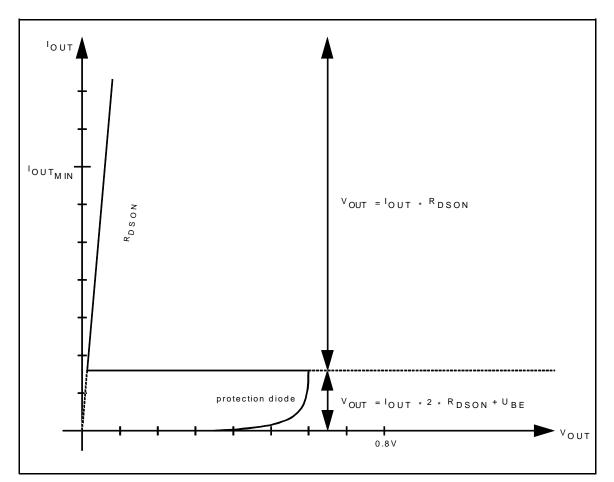
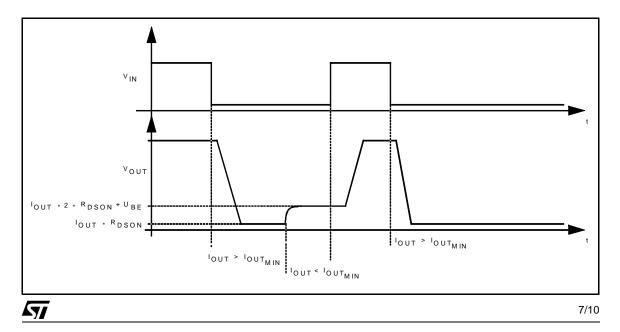


Figure 5: Output Signal Shape Related to Output Current.



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Figure 6: EMS Performance (ISO 9141 BUS system).

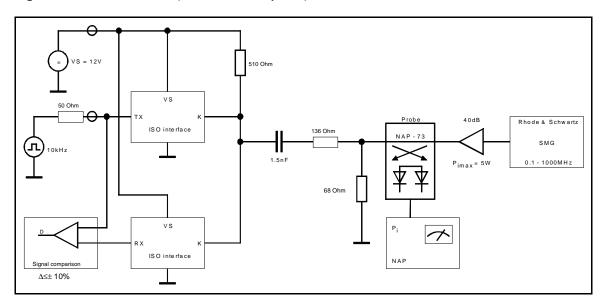
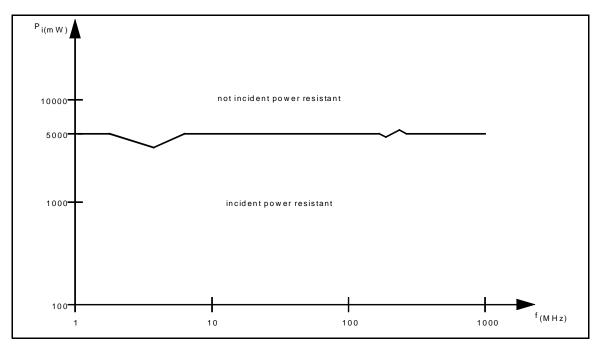
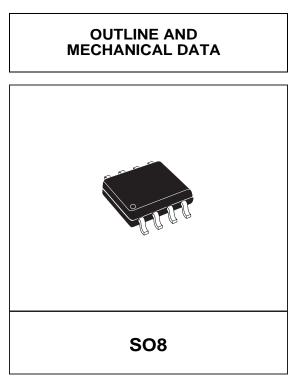


Figure 7.

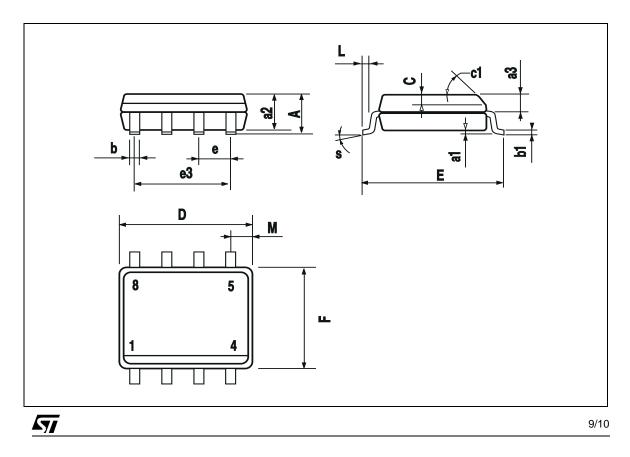


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DIM.	mm			inch			
Dini.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А			1.75			0.069	
a1	0.1		0.25	0.004		0.010	
a2			1.65			0.065	
a3	0.65		0.85	0.026		0.033	
b	0.35		0.48	0.014		0.019	
b1	0.19		0.25	0.007		0.010	
С	0.25		0.5	0.010		0.020	
c1			45° (	(typ.)			
D (1)	4.8		5.0	0.189		0.197	
Е	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		3.81			0.150		
F (1)	3.8		4.0	0.15		0.157	
L	0.4		1.27	0.016		0.050	
М			0.6			0.024	
S	8° (max.)						



(1) D and F do not include mold flash or protrusions. Mold flash or potrusions shall not exceed 0.15mm (.006inch).



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